

Product data sheet

1. General description

Planar passivated sensitive gate Silicon Controlled Rectifier in a SOT54 (TO-92) plastic package.

2. Features and benefits

- High voltage capability
- Planar passivated for voltage ruggedness and reliability
- Sensitive gate

3. Applications

- Earth leakage circuit breakers or Ground Fault Circuit Interrupters (GFCI)
- Ignition circuits
- · Low power latching circuits
- Protection circuits / shut-down circuits: lighting ballasts
- Protection circuits / shut-down circuits: Switched Mode Power Supplies

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DRM}	repetitive peak off- state voltage		-	-	800	V
V_{RRM}	repetitive peak reverse voltage		-	-	800	V
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 ^{\circ}C$; $t_p = 8.3 ms$	-	-	10	A
		half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$; Fig. 4; Fig. 5	-	-	9	A
$I_{T(AV)}$	average on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 1</u>	-	-	0.5	Α
I _{T(RMS)}	RMS on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 2;</u> <u>Fig. 3</u>	-	-	0.8	Α
Static chara	acteristics					
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; I_T = 10 \text{ mA}; T_j = 25 ^{\circ}\text{C};$ Fig. 7	1	50	100	μA





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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	Α	anode		A K
2	G	gate		G sym037
3	K	cathode	TO-92 (SOT54)	·

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BT169H	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54			
BT169H/01	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54			
BT169H/L01	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54			

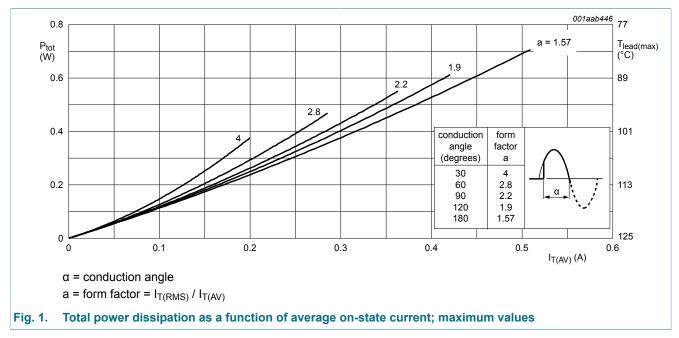
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7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	800	V
V_{RRM}	repetitive peak reverse voltage		-	800	V
I _{T(AV)}	average on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 1</u>	-	0.5	Α
I _{T(RMS)}	RMS on-state current	half sine wave; $T_{lead} \le 83$ °C; Fig. 2; Fig. 3	-	0.8	Α
I _{TSM}	non-repetitive peak on-state current	half sine wave; $T_{j(init)} = 25 ^{\circ}C$; $t_p = 8.3 \text{ms}$	-	10	Α
		half sine wave; $T_{j(init)} = 25 ^{\circ}C$; $t_p = 10 \text{ms}$; Fig. 4; Fig. 5	-	9	А
I ² t	I ² t for fusing	$t_p = 10 \text{ ms; SIN}$	-	0.41	A ² s
dl _T /dt	rate of rise of on-state current	$I_T = 2 \text{ A}$; $I_G = 10 \text{ mA}$; $dI_G/dt = 100 \text{ mA}/$ µs	-	50	A/µs
I _{GM}	peak gate current		-	1	Α
V_{RGM}	peak reverse gate voltage		-	5	V
P_{GM}	peak gate power		-	2	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C



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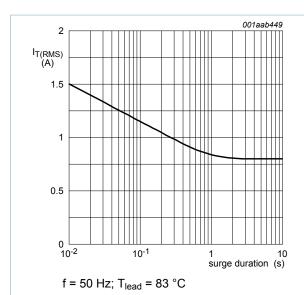


Fig. 2. RMS on-state current as a function of surge duration for sinusoidal currents

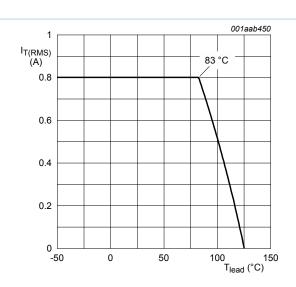


Fig. 3. RMS on-state current as a function of lead temperature; maximum values

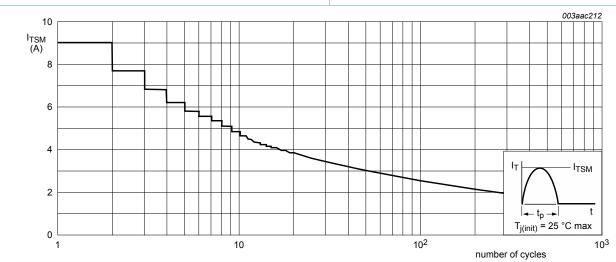


Fig. 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

f = 50 Hz

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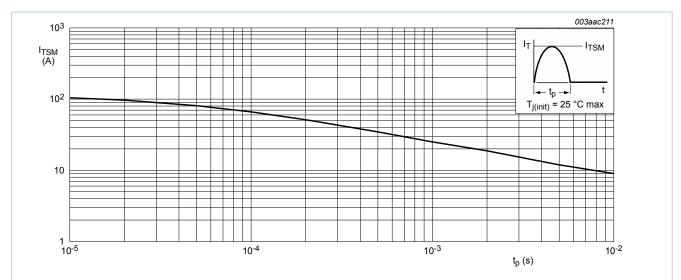


Fig. 5. Non-repetitive peak on-state current as a function of pulse width; maximum values

 $t_p \leq 10 \; ms$

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Thermal characteristics

Table 5. **Thermal characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-lead)}	thermal resistance from junction to lead	Fig. 6	-	-	60	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	printed circuit board mounted: lead length = 4 mm	-	150	-	K/W

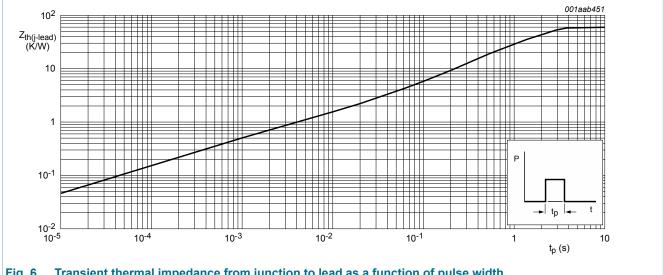


Fig. 6. Transient thermal impedance from junction to lead as a function of pulse width

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9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static char	racteristics		'	'		
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; I_T = 10 \text{ mA}; T_j = 25 ^{\circ}\text{C};$ Fig. 7	1	50	100	μA
IL	latching current	V_D = 12 V; I_G = 0.5 mA; R_{GK} = 1 k Ω ; T_j = 25 °C; Fig. 8	-	2	6	mA
l _H	holding current	$V_D = 12 \text{ V}; R_{GK} = 1 \text{ k}\Omega; T_j = 25 \text{ °C};$ Fig. 9	-	1.5	3	mA
V _T	on-state voltage	I _T = 1.2 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.25	1.7	V
V_{GT}	gate trigger voltage	$V_D = 12 \text{ V}; I_T = 10 \text{ mA}; T_j = 25 \text{ °C};$ Fig. 11	-	0.5	0.8	V
		$V_D = 800 \text{ V}; I_T = 10 \text{ mA}; T_j = 125 ^{\circ}\text{C};$ Fig. 11	0.3	0.5	-	V
I _D	off-state current	$V_D = 800 \text{ V}; T_j = 125 \text{ °C}; R_{GK} = 1 \text{ k}\Omega$	-	0.05	0.1	mA
I _R	reverse current	$V_R = 800 \text{ V}; T_j = 125 \text{ °C}; R_{GK} = 1 \text{ k}\Omega$	-	0.05	0.1	mA
Dynamic c	haracteristics			'		
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T_j = 125 °C; R_{GK} = 1 k Ω ; (V_{DM} = 67% of V_{DRM}); exponential waveform; Fig. 12	150	350	-	V/µs
t _{gt}	gate-controlled turn-on time	I_{TM} = 2 A; V_D = 800 V; I_G = 10 mA; $dI_G/$ dt = 0.1 A/µs; T_j = 25 °C	-	2	-	μs
t _q	commutated turn-off time	V_{DM} = 536 V; T_j = 125 °C; I_{TM} = 1.6 A; V_R = 35 V; $(dI_T/dt)_M$ = 30 A/µs; dV_D/dt = 2 V/µs; R_{GK} = 1 k Ω ; $(V_{DM}$ = 67% of $V_{DRM})$	-	100	-	μs

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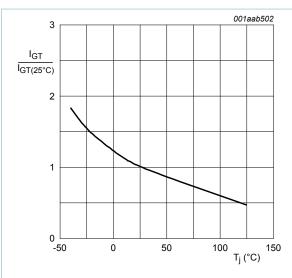


Fig. 7. Normalized gate trigger current as a function of junction temperature

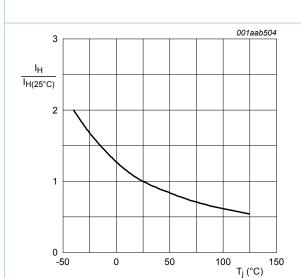
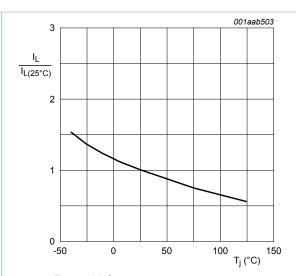


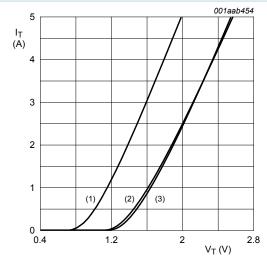
Fig. 9. Normalized holding current as a function of junction temperature

 $R_{GK} = 1 k\Omega$



 $R_{GK} = 1 k\Omega$

Fig. 8. Normalized latching current as a function of junction temperature



Vo = 1.067 V; Rs = 0.187 Ω

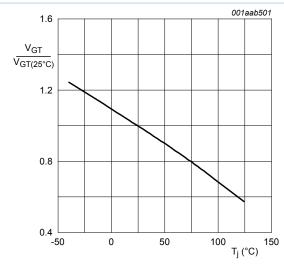
(1) Tj = 125 °C; typical values

(2) Tj = 125 °C; maximum values

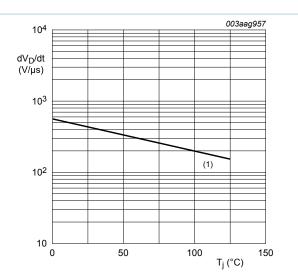
(3) Tj = 25 °C; maximum values

Fig. 10. On-state current as a function of on-state voltage

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function of junction temperature; minimum values

(1)
$$R_{GK} = 1 k\Omega$$

10. Package outline

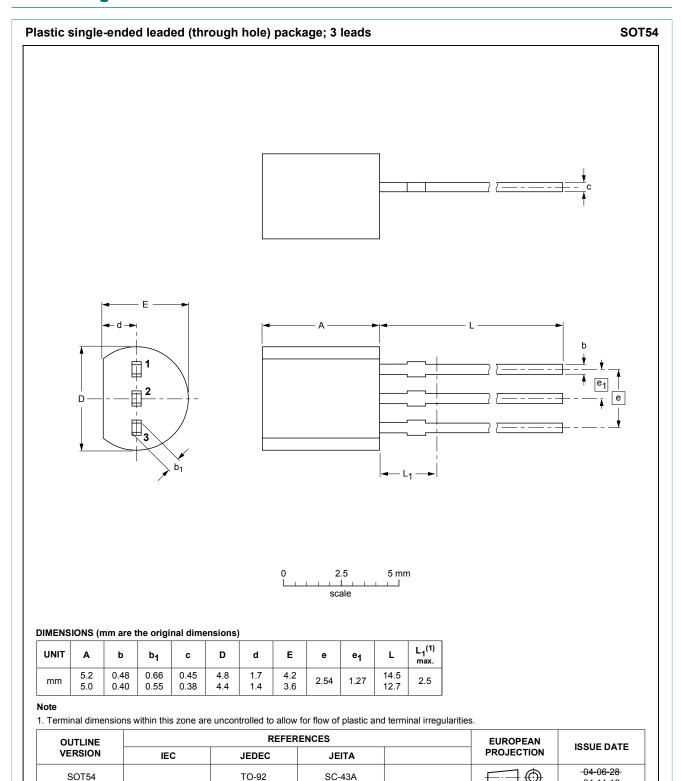


Fig. 13. Package outline TO-92 (SOT54)

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